

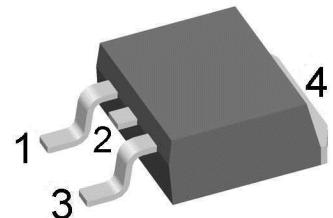
# High Efficiency Thyristor

$V_{RRM}$  = 800 V  
 $I_{TAV}$  = 20 A  
 $V_T$  = 1.31 V

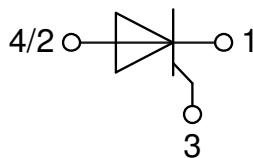
## Single Thyristor

### Part number

**CS19-08ho1S**



Backside: anode



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

### Terms & Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you.

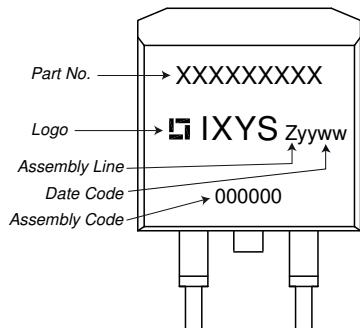
Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you. Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			900	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ\text{C}$			800	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 800 \text{ V}$ $V_{R/D} = 800 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		50 1	$\mu\text{A}$ mA
$V_T$	forward voltage drop	$I_T = 20 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.32	V
		$I_T = 40 \text{ A}$			1.65	V
		$I_T = 20 \text{ A}$ $I_T = 40 \text{ A}$	$T_{VJ} = 125^\circ\text{C}$		1.31 1.73	V
$I_{TAV}$	average forward current	$T_C = 110^\circ\text{C}$	$T_{VJ} = 125^\circ\text{C}$		20	A
$I_{T(RMS)}$	RMS forward current	180° sine			31	A
$V_{T0}$ $r_T$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 125^\circ\text{C}$		0.86 22	V $\text{m}\Omega$
$R_{thJC}$	thermal resistance junction to case				0.7	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.50		K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ\text{C}$		170	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		180	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		195	A
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 125^\circ\text{C}$		155	A
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		165	A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ\text{C}$		160	$\text{A}^2\text{s}$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		160	$\text{A}^2\text{s}$
		$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$	$T_{VJ} = 125^\circ\text{C}$		120	$\text{A}^2\text{s}$
		$t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$V_R = 0 \text{ V}$		115	$\text{A}^2\text{s}$
$C_J$	junction capacitance	$V_R = 230 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		9	pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu\text{s}$	$T_C = 125^\circ\text{C}$		5	W
		$t_p = 300 \mu\text{s}$			2.5	W
					0.5	W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 150^\circ\text{C}; f = 50 \text{ Hz}$ repetitive, $I_T = 60 \text{ A}$			150	$\text{A}/\mu\text{s}$
		$t_p = 200 \mu\text{s}; di_G/dt = 0.15 \text{ A}/\mu\text{s};$				
		$I_G = 0.15 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 20 \text{ A}$			500	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ\text{C}$		500	$\text{V}/\mu\text{s}$
		$R_{GK} = \infty$ ; method 1 (linear voltage rise)				
$V_{GT}$	gate trigger voltage	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		1.5	V
			$T_{VJ} = -40^\circ\text{C}$		2.5	V
$I_{GT}$	gate trigger current	$V_D = 6 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$		28	mA
			$T_{VJ} = -40^\circ\text{C}$		50	mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 150^\circ\text{C}$		0.2	V
$I_{GD}$	gate non-trigger current				3	mA
$I_L$	latching current	$t_p = 10 \mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$		75	mA
		$I_G = 0.1 \text{ A}; di_G/dt = 0.1 \text{ A}/\mu\text{s}$				
$I_H$	holding current	$V_D = 6 \text{ V}$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ\text{C}$		50	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	$T_{VJ} = 25^\circ\text{C}$		2	$\mu\text{s}$
		$I_G = 0.1 \text{ A}; di_G/dt = 0.1 \text{ A}/\mu\text{s}$				
$t_q$	turn-off time	$V_R = 100 \text{ V}; I_T = 20 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 100^\circ\text{C}$		150		$\mu\text{s}$
		$di/dt = 10 \text{ A}/\mu\text{s}$ $dv/dt = 20 \text{ V}/\mu\text{s}$ $t_p = 200 \mu\text{s}$				

**Package TO-263 (D2Pak)**

Symbol	Definition	Conditions	Ratings		
			min.	typ.	max.
$I_{RMS}$	$RMS$ current	per terminal			35 A
$T_{VJ}$	virtual junction temperature		-40		125 °C
$T_{op}$	operation temperature		-40		100 °C
$T_{stg}$	storage temperature		-40		150 °C
<b>Weight</b>				2 g	
$F_c$	mounting force with clip		20		60 N

**Product Marking**

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CS19-08ho1S	CS19-08ho1S	Tape & Reel	800	489204
Alternative	CS19-08ho1S-TUB	CS19-08ho1S	Tube	50	473332

Similar Part	Package	Voltage class
CS19-08ho1	TO-220AB (3)	800
CS19-12ho1	TO-220AB (3)	1200
CS19-12ho1S	TO-263AB (D2Pak) (2)	1200

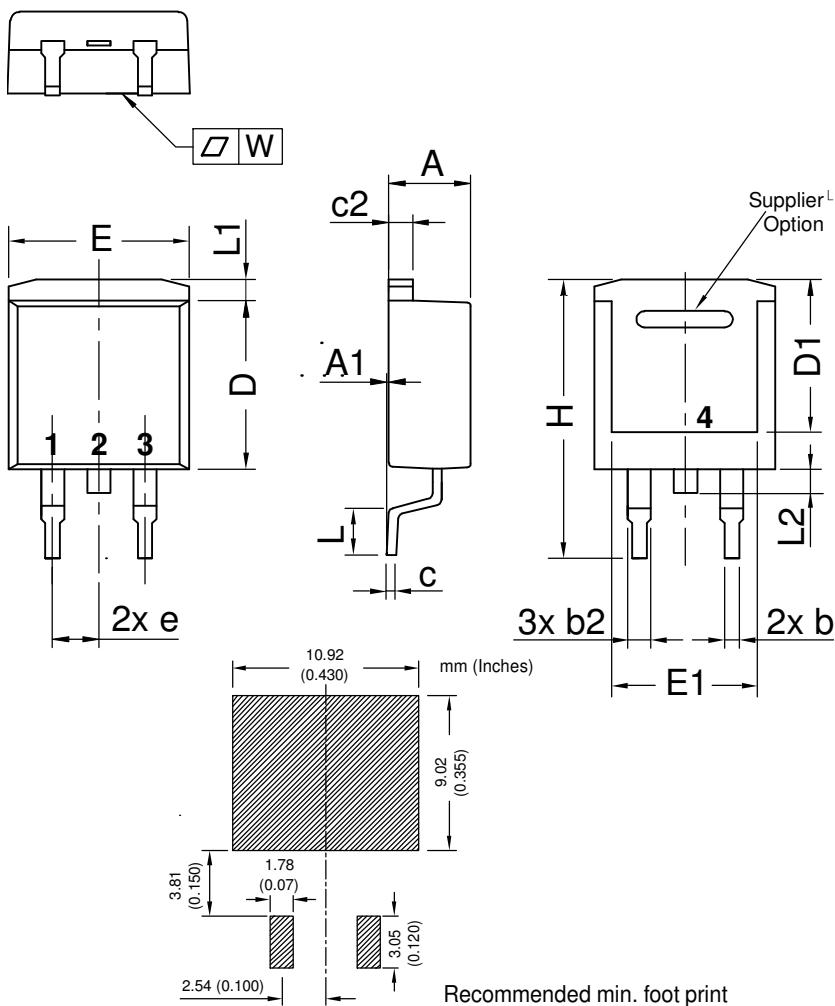
**Equivalent Circuits for Simulation**

\* on die level

 $T_{VJ} = 125$  °C

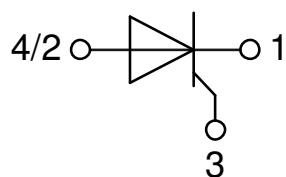
	Thyristor
$V_{0\max}$	threshold voltage 0.86 V
$R_{0\max}$	slope resistance * 19 mΩ

## Outlines TO-263 (D2Pak)



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

All dimensions conform with  
and/or within JEDEC standard.



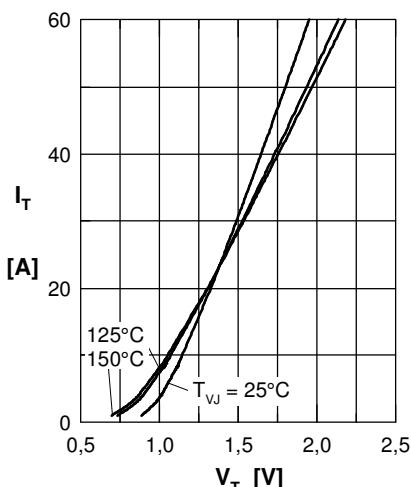
**Thyristor**

Fig. 1 Forward characteristics

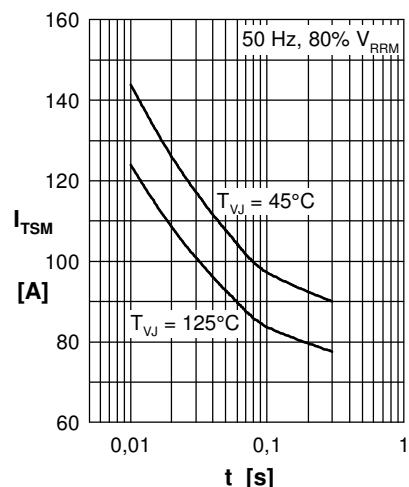


Fig. 2 Surge overload current

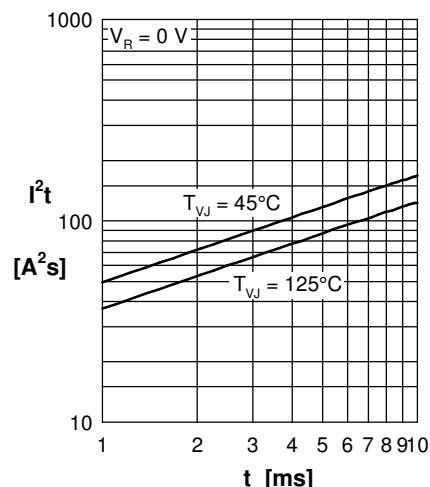
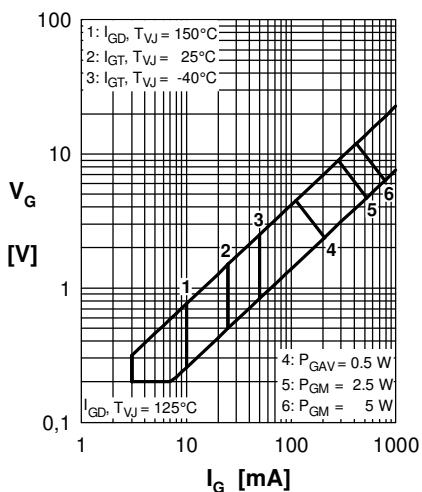
Fig. 3  $I^2t$  versus time (1-10 ms)

Fig. 4 Gate trigger characteristics

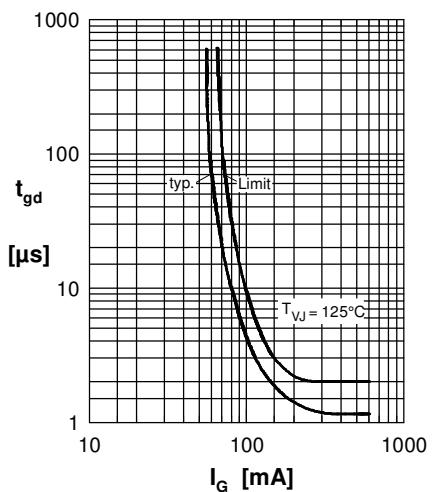


Fig. 5 Gate controlled delay time

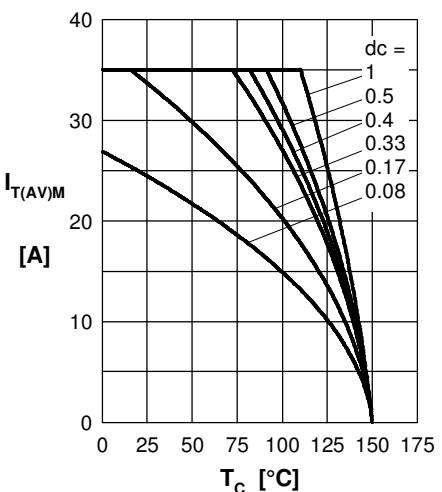


Fig. 6 Max. forward current at case temperature

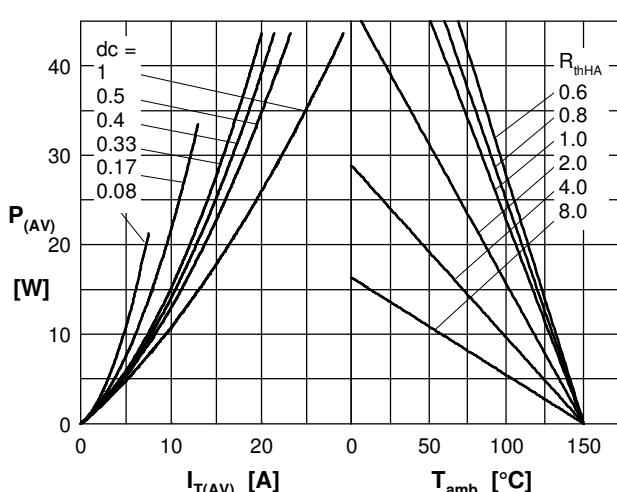
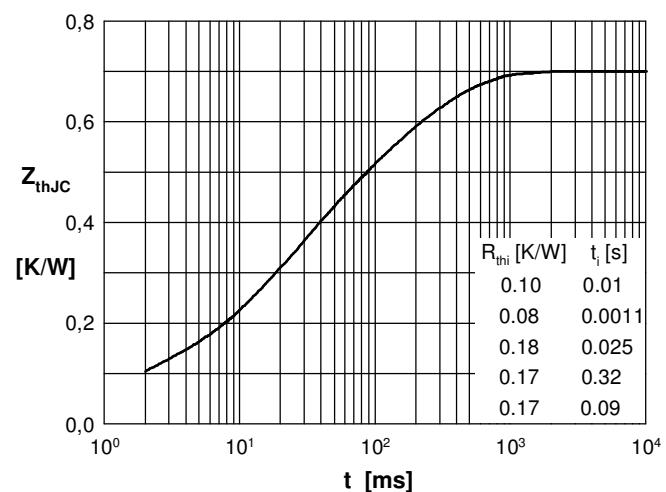
Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

Fig. 8 Transient thermal impedance junction to case

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